NSN 5962-01-161-3498

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches a	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Diss	ipation Rating:
739.0 milliwatts	
Operating Tempuratur	re Range:
-55.0/+125.0 degrees c	elsius
Storage Tempurature	Range:
65.0/+150.0 degrees c	elsius
End Application:	
An/fps-117 radar syster	n
Features Provided:	
Hermetically sealed and	d burn in and bipolar and schottky and programmable and w/enable and w/active pull-up
nclosure Material:	
Ceramic	
nclosure Configuratio	on:
Dual-in-line	
Dutput Logic Form:	
Fransistor-transistor log	,ic
nput Circuit Pattern:	
0 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Ferminal Surface Trea	itment:
Solder	
/oltage Rating And Ty	ype Per Characteristic:
5.5 volts power source	
Time Rating Per Chac	teristic:
75.00 nanoseconds pro	opagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Qu	Jantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

